TEXAS INSTRUMENTS

LDC0851 差動型誘導性スイッチ

1 特長

- 機能安全対応
  - 機能安全システムの設計に役立つ資料を利用可能
- スレッショルドの許容誤差:< コイル直径の 1%
- 温度に対して安定なスイッチング動作
- 平均電源電流: 10sps で < 20µA
- シャットダウン時の電源電流:140nA
- プッシュ プル出力
- スレッショルドを抵抗によりプログラム可能
- DC 磁界の影響を受けない
- 非接触スイッチ動作
- 最大 4ksps のサンプリング レート
- 電源電圧:1.8V〜3.3V
- 動作温度範囲:-40〜125 ℃

2 アプリケーション

- イベント計数
  - ファン速度 RPM 検出
  - インクリメンタルエンコーダ / ノブ
- 開閉スイッチ
  - ホーム・セキュリティおよび改ざん検出
- 産業用近接スイッチ

3 概要

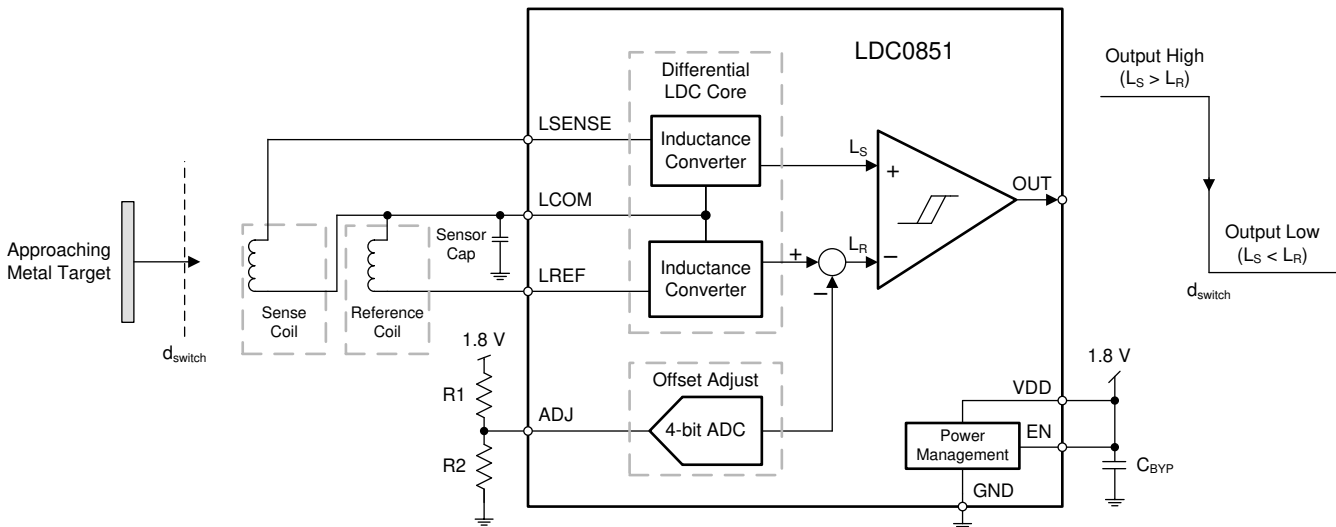LDC0851 は、存在検出やイベント計数など、非接触型のシンプルなスイッチ アプリケーションに最適な近距離誘導性スイッチです。

このスイッチは、導電性の物体が検出コイルのすぐ近くに来るとトリガされます。信頼性の高いスイッチング スレッショルドを確保するため、ヒステリシスを備えています。差動実装は、温度変化や湿度効果などの環境要因による誤トリガを防止します。LDC0851 は 動作に MCU を必要としないため、単純なソリューションを実現できます。

誘導性センシング技術は、ちり、油、湿気が存在する環境下でも、信頼性と精度の高いセンシングを実現するので、過酷または汚れの多い環境での使用に最適です。半導体スイッチは機械式または接触式スイッチに起因する障害を解消します。LDC0851 は、競合製品とは違って磁石を必要とせず、DC 磁界の影響も受けません。

パッケージ情報

部品番号	パッケージ [1]	パッケージ サイズ [2]
LDC0851	DSG (WSON、8)	2mm × 2mm

(1) 利用可能なすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。

(2) パッケージ サイズ (長さ × 幅) は公称値であり、該当する場合はピンも含まれます。

概略回路図

English Data Sheet: SNOSCZ7

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4 Pin Configuration and Functions
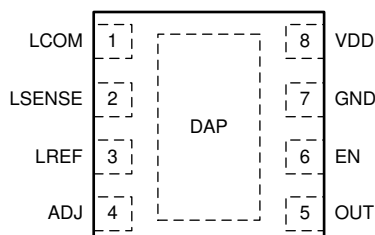
図 4-1. DSG Package 8-Pin WSON with DAP Top View

表 4-1. Pin Functions

PIN		TYPE[1]	DESCRIPTION
NAME	NO.		
LCOM	1	A	Common coil input
LSENSE	2	A	Sense coil input
LREF	3	A	Reference coil input
ADJ	4	A	Threshold adjust pin
OUT	5	O	Switch output
EN	6	I	Enable input
GND	7	G	Ground
VDD	8	P	Power Supply
DAP	DAP	G	Connect to Ground for improved thermal performance[2]

(1)   I = Input, O = Output, P = Power, A = Analog, G = Ground

(2)   There is an internal electrical connection between the exposed Die Attach Pad (DAP) and the GND pin of the device. Although the DAP can be left floating, for best performance the DAP should be connected to the same potential as the device's GND pin. Do not use the DAP as the primary ground for the device. The device GND pin must always be connected to ground.

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) [1]

		MIN	MAX	UNIT
V_{DD}	Supply Voltage Range		3.6	V
V_i	Voltage on LSENSE, LREF, and EN	-0.3	3.6	V
	Voltage on ADJ and LCOM	-0.3	2	V
I_A	Current LSENSE, LREF, and VOUT		5	mA
T_J	Junction Temperature	-55	150	°C
T_{stg}	Storage Temperature	-65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001[1]	±1000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101[2]	±250	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{DD}	Supply Voltage	1.71		3.46	V
T_A	Operating Temperature	-40		125	°C

5.4 Thermal Information

over operating free-air temperature range (unless otherwise noted)

THERMAL METRIC[1]		LDC0851 DSG (WSON) 8 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	67.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	89.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	37.3	°C/W
ψ_{JT}	Junction-to-top characterization parameter	2.4	°C/W
ψ_{JB}	Junction-to-board characterization parameter	37.7	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	9.2	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report (SPRA953).

5.5 Electrical Characteristics

Over recommended operating conditions unless otherwise noted. V_{DD}= 3.3 V, EN tied to 3.3 V, T_A=25 °C, ADJ tied to GND.[1]

PARAMETER		TEST CONDITIONS	MIN[2]	TYP[3]	MAX[2]	UNIT
POWER						
V_{DD}	Supply Voltage		1.71		3.46	V
I_{STATIC}	Static Supply Current [4]			0.70		mA
I_{DYN}	Dynamic Supply Current (not including sensor current)[4]	f_{SENSOR} = 15 MHz $C_{PARASITIC}$ = 22 pF		0.66		mA
I_{SD}	Shutdown Mode Supply Current			0.14	1	µA
SENSOR						
I_{SENSOR_MAX}	Maximum sensor current[4]	V_{DD} = 1.71 V		4.35		mA
		V_{DD} = 3.3 V		6		mA
L_{SENSOR_MIN}	Sensor Minimum Inductance[5]	C_{TOTAL} = 33 pF V_{DD} = 1.71 V		2.5		
		C_{TOTAL} = 33 pF V_{DD} = 3.3 V		1.8		µH
f_{SENSOR_MAX}	Max Sensor Resonant Frequency[5]	Sensor inductance = 2 µH C_{TOTAL} = 33 pF		19		MHz
C_{TOTAL}	Minimum total capacitance on LCOM[5] Includes parasitic pin capacitance and PCB parasitic capacitance			33		pF
C_{IN}	Pin parasitic capacitance on LCOM			12		pF
	Pin parasitic capacitance on LREF and LSENSE			8		pF
DETECTION						
d_{HYST}	Switching distance hysteresis[6]			2.5 %		
d_{TOL}	Switching threshold tolerance[6]			0.1 %		
THRESHOLD ADJUST						
V_{ADJ}	Adjust input range		0		$V_{DD}/2$	V
V_{ADJ_TOL}	Adjust threshold tolerance			± 6		mV

(1)   Electrical Characteristics Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that T_J = T_A. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where T_J > T_A. Absolute Maximum Ratings indicate junction temperature limits beyond which the device may be permanently degraded, either mechanically or electrically.

(2)   Limits are ensured by testing, design, or statistical analysis at 25°C. Limits over the operating temperature range are ensured through correlations using statistical quality control (SQC) method.

(3)   Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.

(4)   Refer to section *Active Mode* for a description and calculation of the various supply currents.

(5)   See *Sensor Design* for sensor guidance.

(6)   Two matched 10 mm diameter sensors were used with a switching distance of 3 mm. See *Hysteresis* for more information.

5.6 Interface Voltage Levels

PARAMETER		MIN	TYP	MAX	UNIT
V_{IH}	Input High Voltage	$0.8^x V_{DD}$			V
V_{IL}	Input Low Voltage			$0.2^x V_{DD}$	V
V_{OH}	Output High Voltage(1mA source current)	V_{DD}-0.4			V
V_{OL}	Output Low Voltage (1mA sink current)			0.4	V

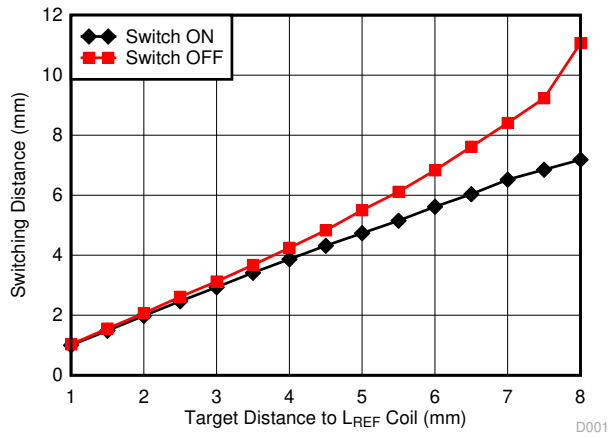## 5.7 Timing Requirements

Over recommended operating conditions unless otherwise noted. V_{DD}= 3.3 V, EN tied to 3.3 V, T_A=25 °C, ADJ tied to GND.

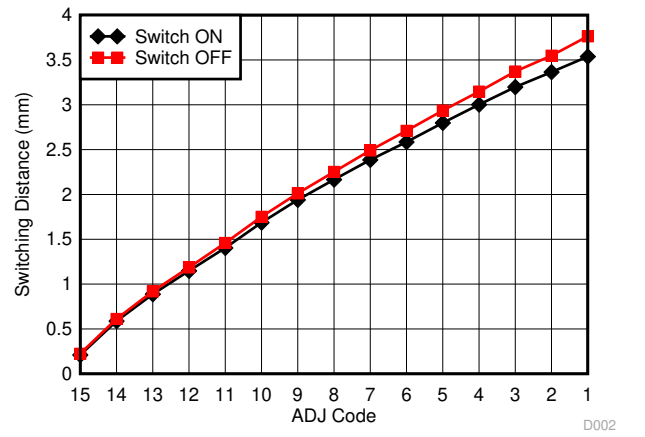| PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
VOLTAGE LEVELS						
$t_{CONVERSION}$	Conversion time	f_{SENSOR} = 15 MHz		290		µs
t_{DELAY}	Output delay time (Response time)	f_{SENSOR} = 15 MHz		580		µs
t_{START}	Start-up time			450		µs
t_{AMT}	Shutdown-to-active mode transition time			450		µs
t_{SMT}	Active-to-shutdown mode transition time			<1		µs

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Product Folder Links: *LDC0851*
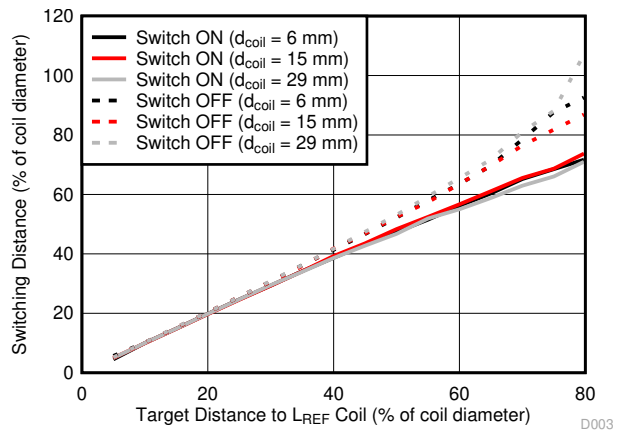
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5.8 Typical Characteristics

Common test conditions (unless specified otherwise): V_{DD} = 3.3 V, Sense coil diameter = reference coil diameter, Target: Aluminum, 1.5 mm thickness, Target area / Coil area > 100%
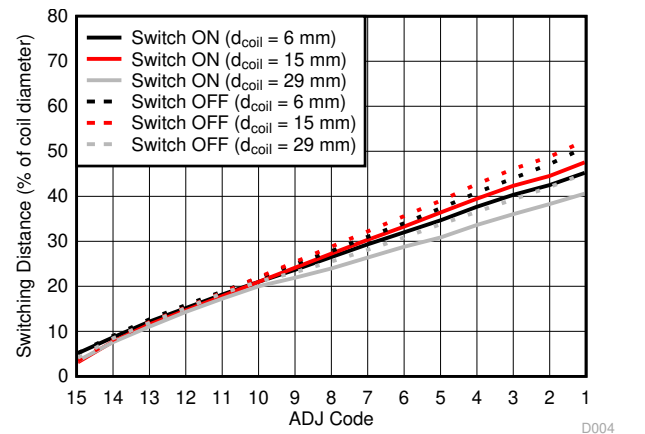

See *Basic Operation Mode*   ADJ Code = 0
Coil diameter = 10 mm

図 5-1. Switching Distance vs. LREF Target Distance

See *Threshold Adjust Mode*   No reference target
Coil diameter = 10 mm

図 5-2. Switching Distance vs. ADJ code

See *Basic Operation Mode*   ADJ Code = 0
Coil diameter = 6 mm, 15 mm, 29 mm

図 5-3. Normalized Switching Distance vs. LREF Target Distance

See *Threshold Adjust Mode*   No reference target
Coil diameter = 6 mm, 15 mm, 29 mm

図 5-4. Normalized Switching Distance vs. ADJ Code

LSENSE frequency (f_s) varied   LREF frequency (f_r) fixed
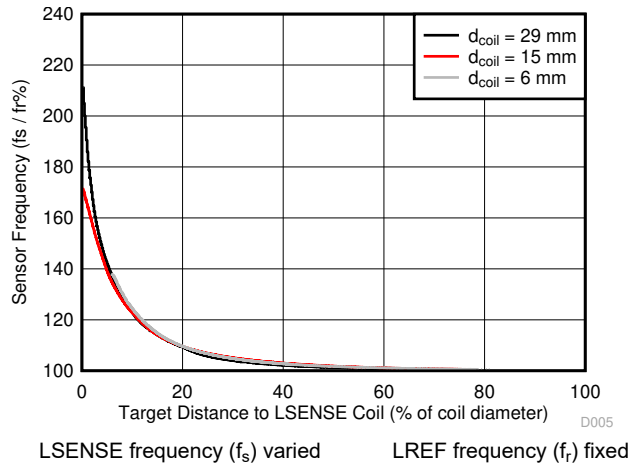
図 5-5. Frequency vs. Distance

LSENSE inductance (L_s) varied   LREF inductance (L_r) fixed
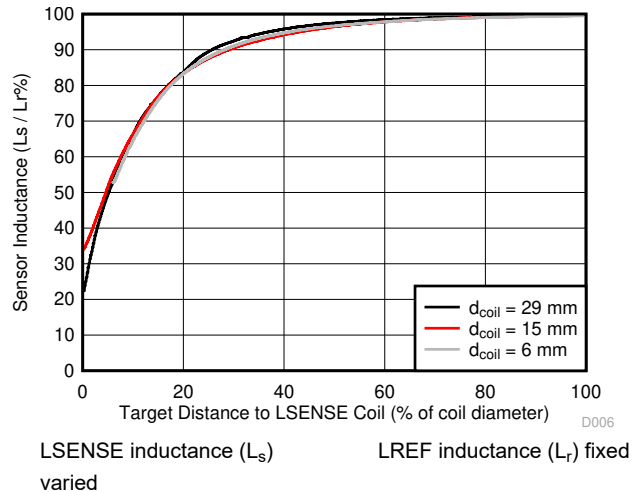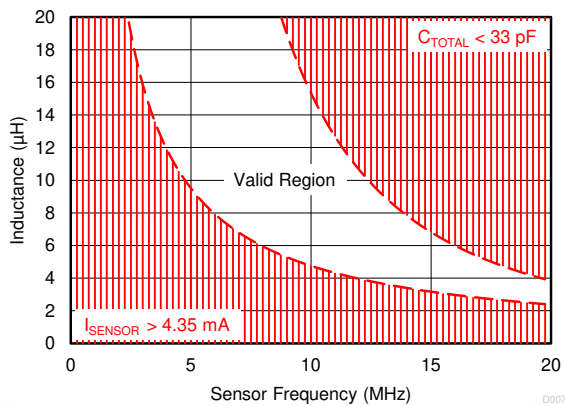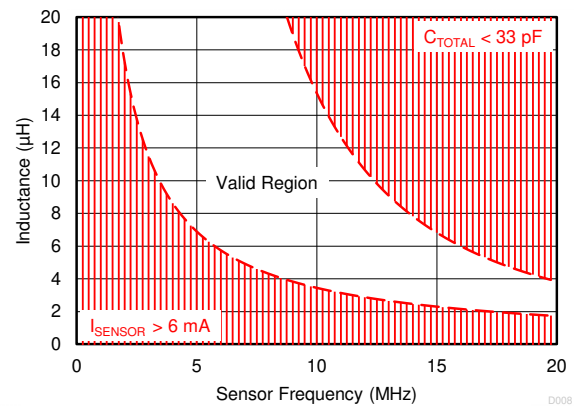
図 5-6. Inductance vs. Distance

I_{SENSOR_MAX} = 4.35 mA

Specified for closest target proximity or minimum inductance in the application.

図 5-7. Sensor Design Space for V_{DD} = 1.8 V

I_{SENSOR_MAX} = 6 mA

Specified for closest target proximity or minimum inductance in the application.
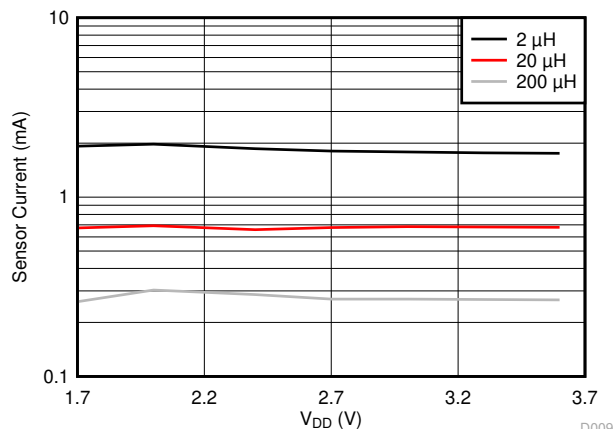
図 5-8. Sensor Design Space for V_{DD} = 3.3 V

C_{TOTAL} = 100 pF

図 5-9. I_{SENSOR} vs. V_{DD}

C_{BOARD} = 12 pF

f_{SENSOR} = 30 MHz

図 5-10. I_{DYN} vs. V_{DD}

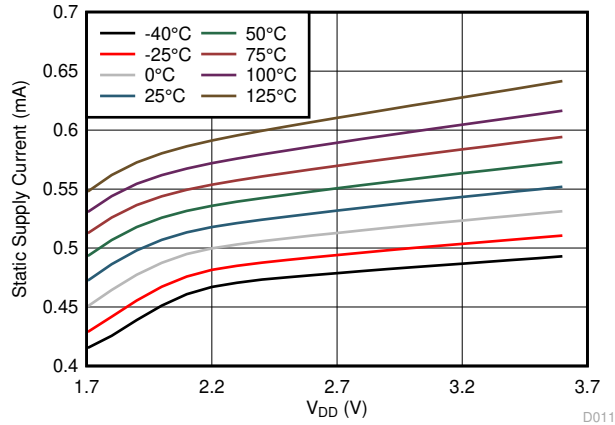Product Folder Links: *LDC0851*

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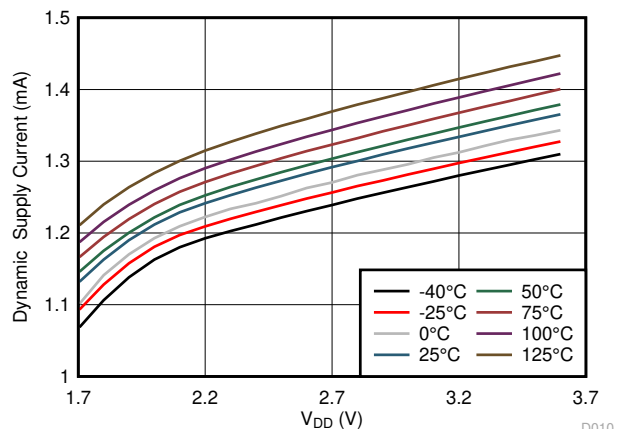
図 5-11. I_{STATIC} vs. V_{DD}
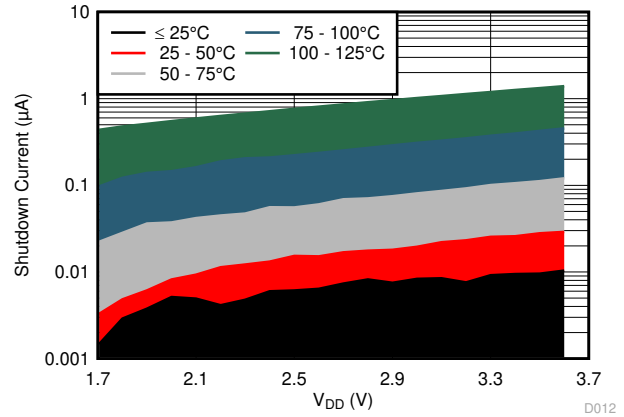
図 5-12. I_{SD} vs. V_{DD}
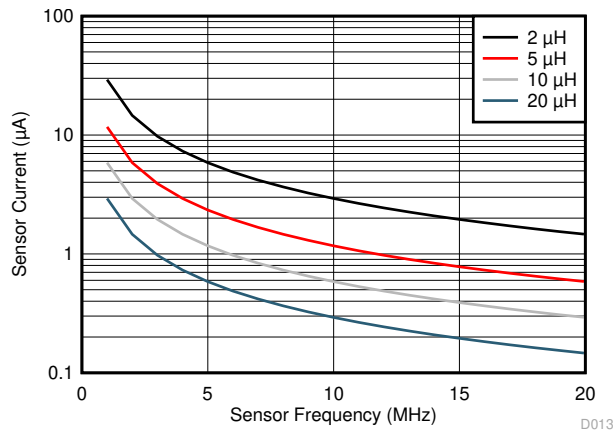
See 式 4

図 5-13. I_{SENSOR} vs. f_{SENSOR}

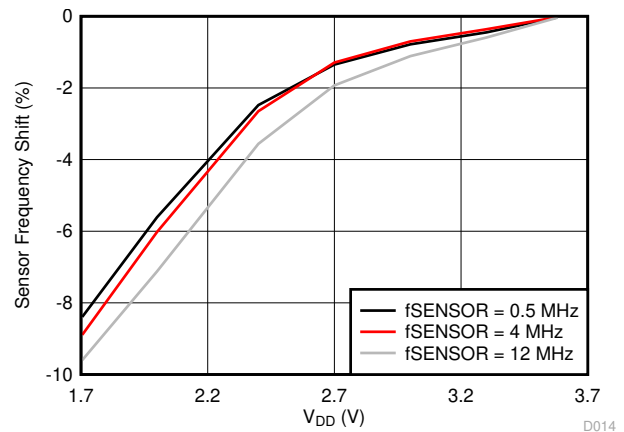Normalized to frequency at V_{DD} = 3.6 V

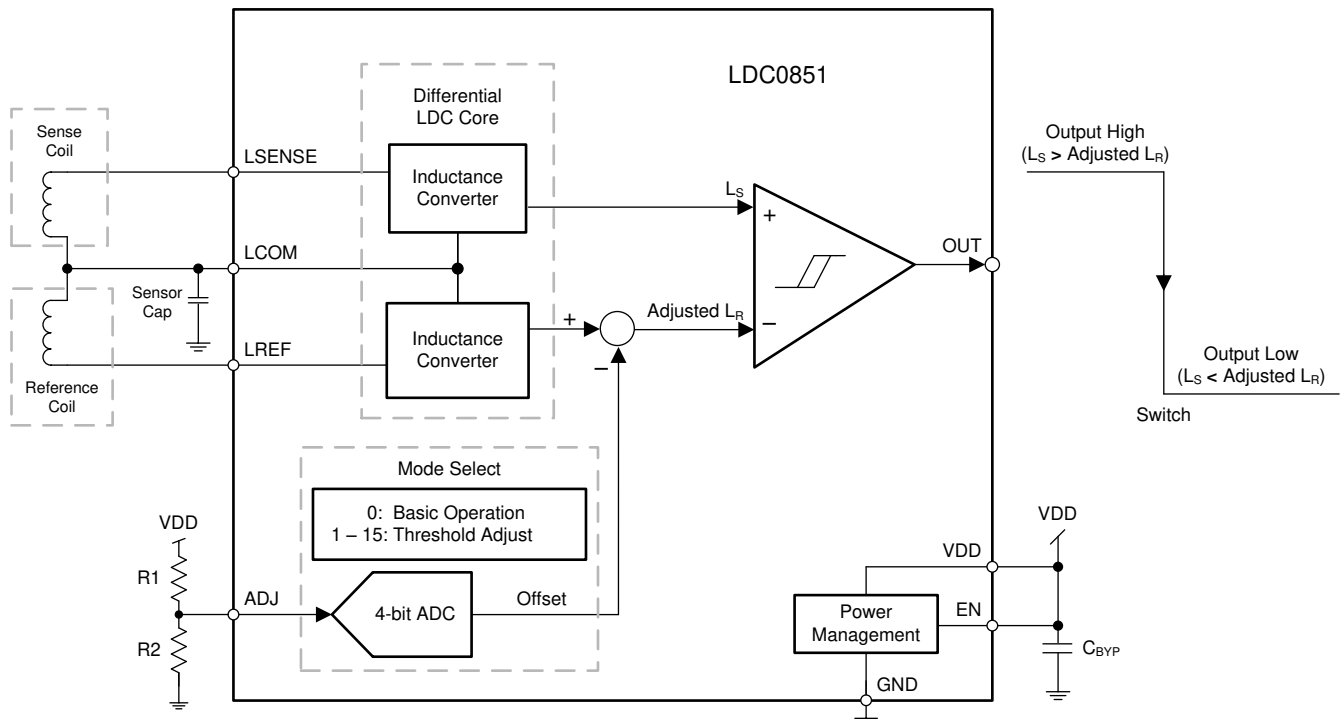図 5-14. f_{SENSOR} Shift vs. V_{DD}

6 Detailed Description

6.1 Overview

The LDC0851 is an inductance comparator with push/pull output. It utilizes a sensing coil and a reference coil to determine the relative inductance in a system. The push/pull output (OUT) switches low when the sense inductance drops below the reference and returns high when the reference inductance is higher than the sense inductance. Matching the sense and reference coils is important to maintain a consistent switching distance over temperature and to compensate for other environmental factors. The LDC0851 features internal hysteresis to prevent false switching due to noise or mechanical vibration at the switching threshold. The switching threshold is set by the sensor characteristics and proximity to conductive objects, which is considered Basic Operation Mode described further in section *Basic Operation Mode*. The LDC0851 also features a Threshold Adjust Mode where an offset is subtracted from the reference inductance to change the effective switching point as described in section *Threshold Adjust Mode*.

The sensing coil is connected across the LSENSE and LCOM pins and the reference coil is connected across the LREF and LCOM pins. A sensor capacitor is connected from LCOM to GND to set the sensor oscillation frequency. The sensor capacitor is common to both LSENSE and LREF making the inductance measurement differential.

6.2 Functional Block Diagram

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6.3 Feature Description

6.3.1 Basic Operation Mode

The LDC0851 is configured for Basic Operation mode when the ADJ pin is tied to ground. Two identical coils should be used for LSENSE and LREF. The switching point occurs when the inductances of both coils are equal. Basic Operation mode can be used for a wide variety of applications including event counting, sliders, or proximity sensing. An example showing gear tooth counting can be found in section *Event Counting*.

For proximity sensing the switching point can be set by placing a conductive target at a fixed distance from the reference coil as shown in 図 6-1. The output will switch when a conductive target approaches LSENSE and reaches the same distance set by the fixed reference target. For reliable and repeatable switching it is recommended to place the reference target at a distance less than 40% of the coil diameter from the reference coil.
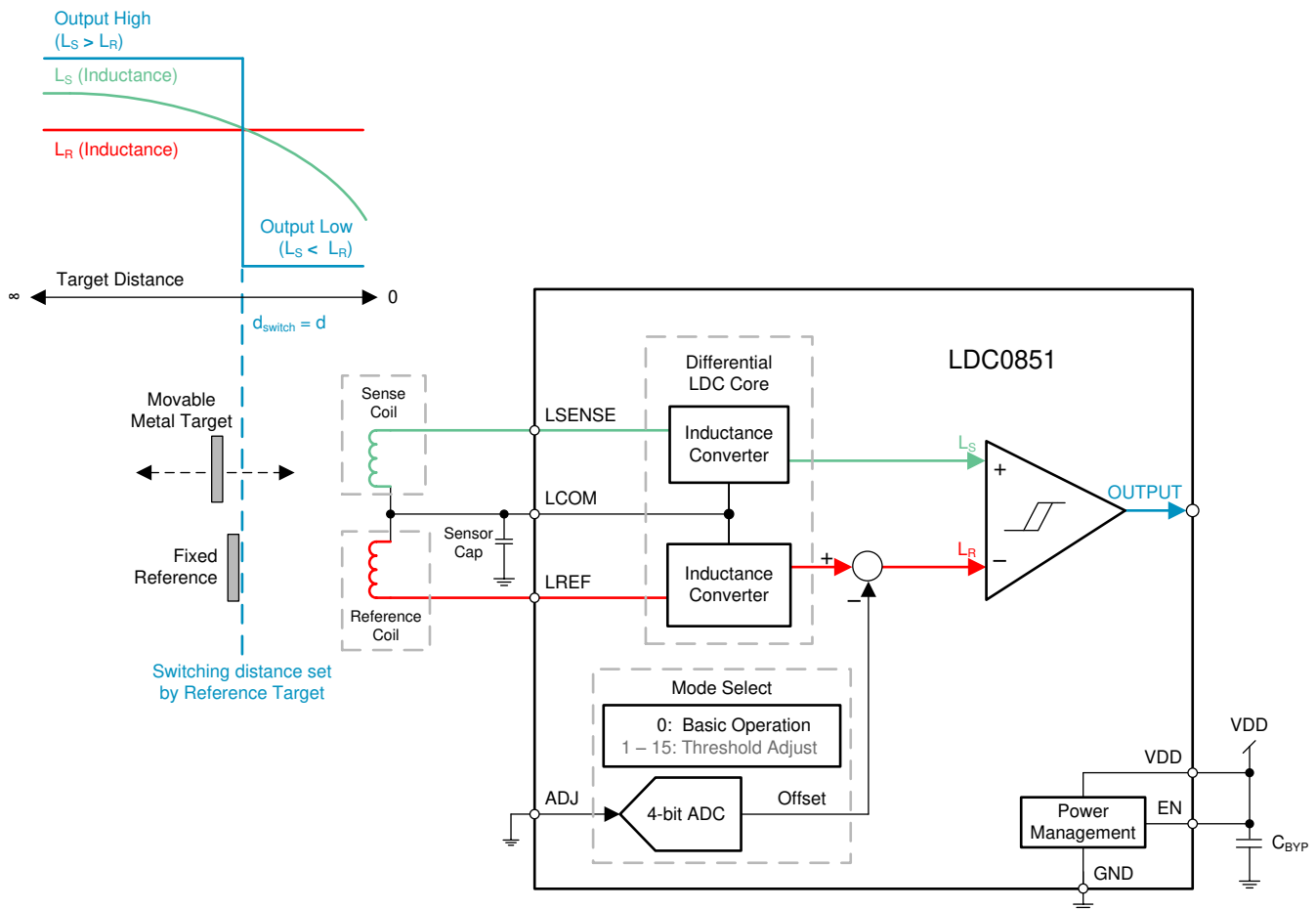

図 6-1. Basic Operation Mode Diagram for Distance Sensing With Reference Target

In some systems adding a reference target at a fixed height to set the switching distance is not feasible. Therefore to set the switching distance a small amount of mismatch between the sense and reference coils can be introduced. To achieve the maximum switching distance the reference inductance should be approximately 0.4% less than the sense inductance as shown in 図 6-2 below. The 0.4% mismatch will ensure that the output will switch off when the target is removed.
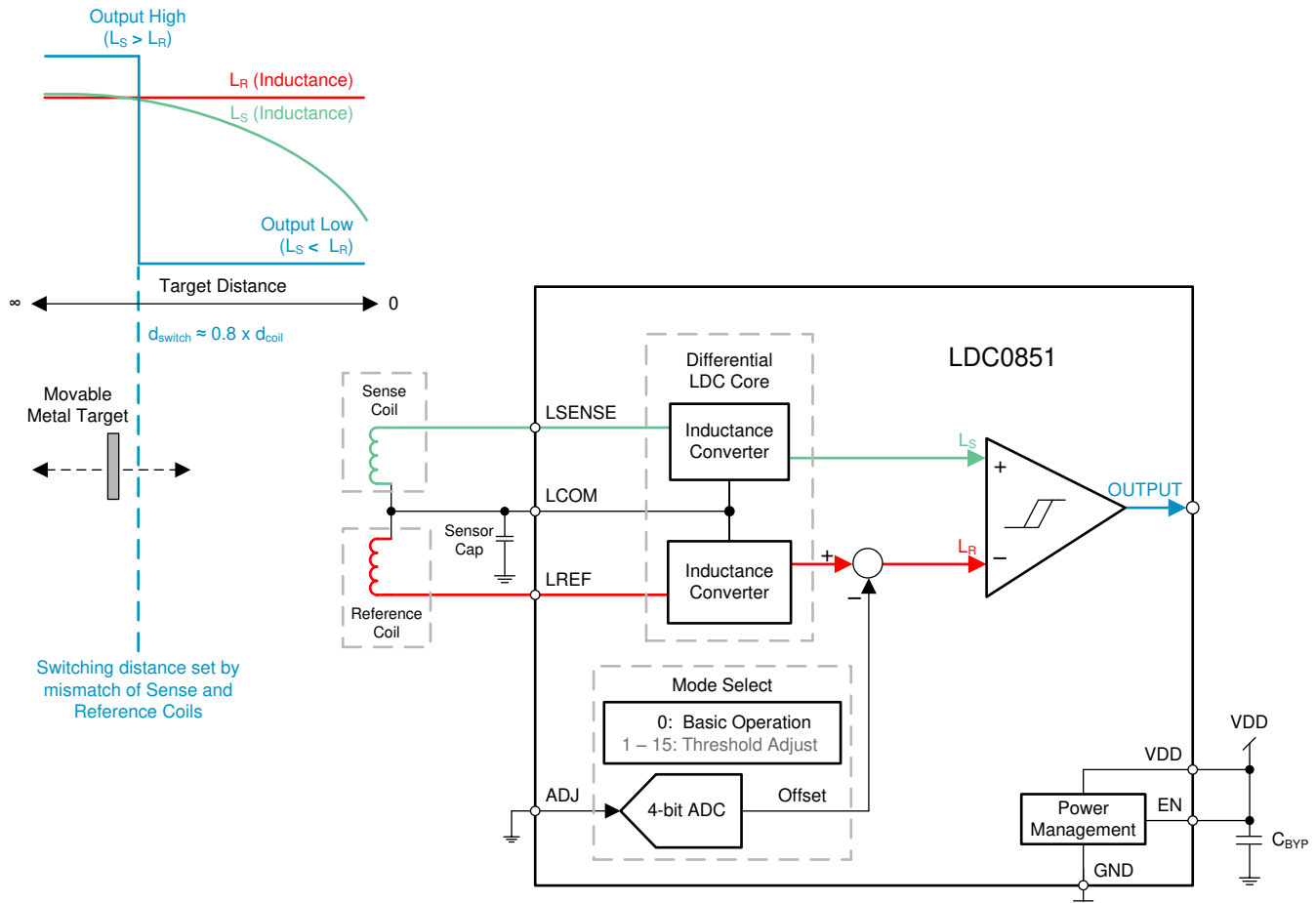

図 6-2. Basic Operation Mode Diagram for Distance Sensing With Mismatched Coils

6.3.2 Threshold Adjust Mode

In Threshold Adjust mode, an offset inductance is subtracted from LREF to alter the switching threshold without the use of a reference target. In order to configure the LDC0851 for Threshold Adjust mode, place a resistor divider between VDD and GND as shown in 図 6-3. The threshold adjust values can then be easily changed as described in section *Setting the Threshold Adjust Values*. Threshold adjust mode can be used in a variety of applications including coarse proximity sensing and simple button applications as shown in *Coarse Position Sensing*. Two example coil configurations for proximity sensing are shown below for side by side coil orientation in 図 6-3 as well as a stacked configuration in 図 6-4.
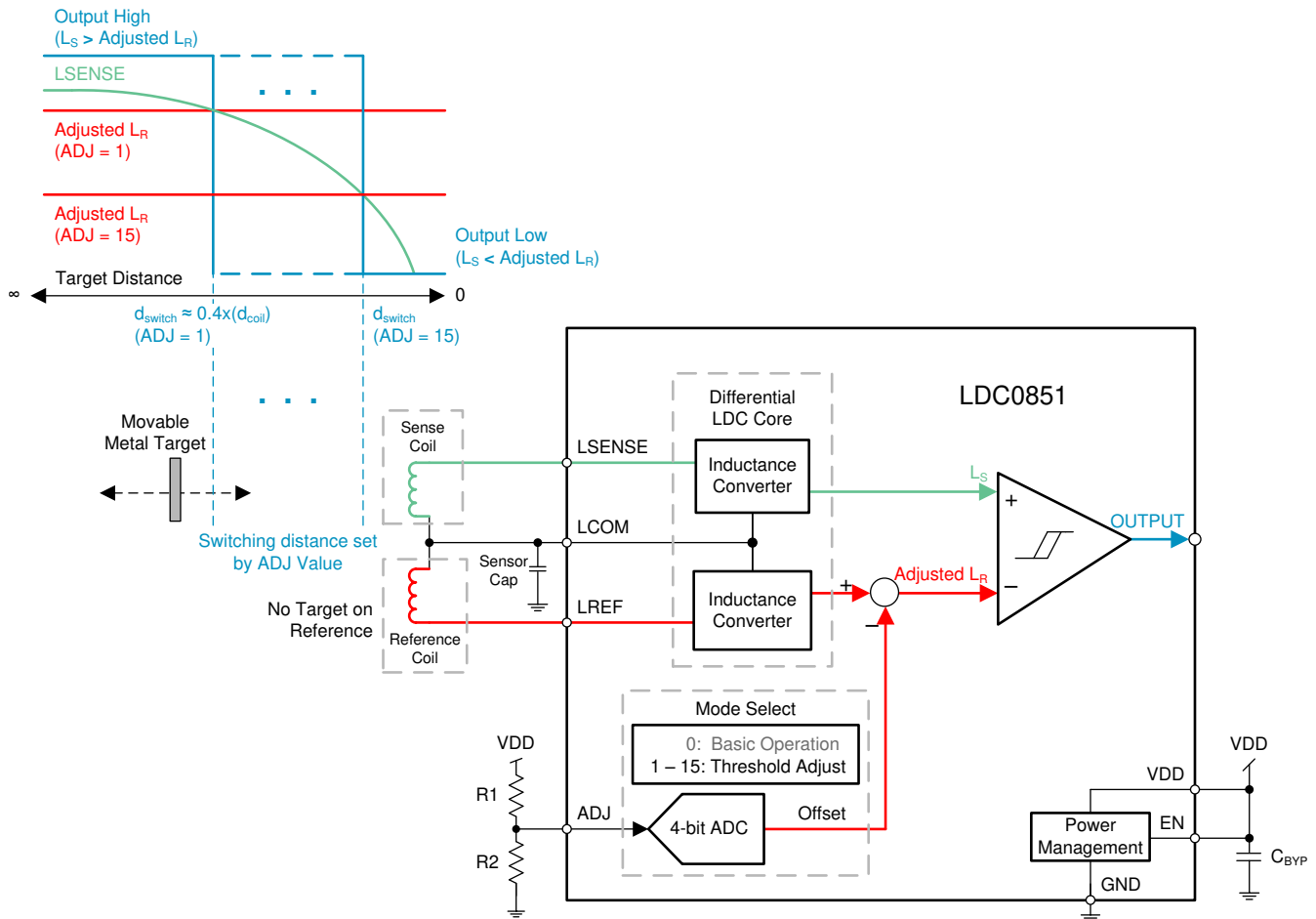

図 6-3. Threshold Adjust Mode for Distance Sensing Using Side by Side Coils

Stacked coils can be utilized in designs where PCB space is a concern or if the user only wants to detect proximity to metal from one side of the PCB such as a button application. The sensing range is slightly reduced due to the fact that both the sense and the reference coil are affected by same conductive target, however since the sense coil is closer to the target its respective inductance decreases more than the reference inductance allowing the output to switch as shown in 図 6-4.

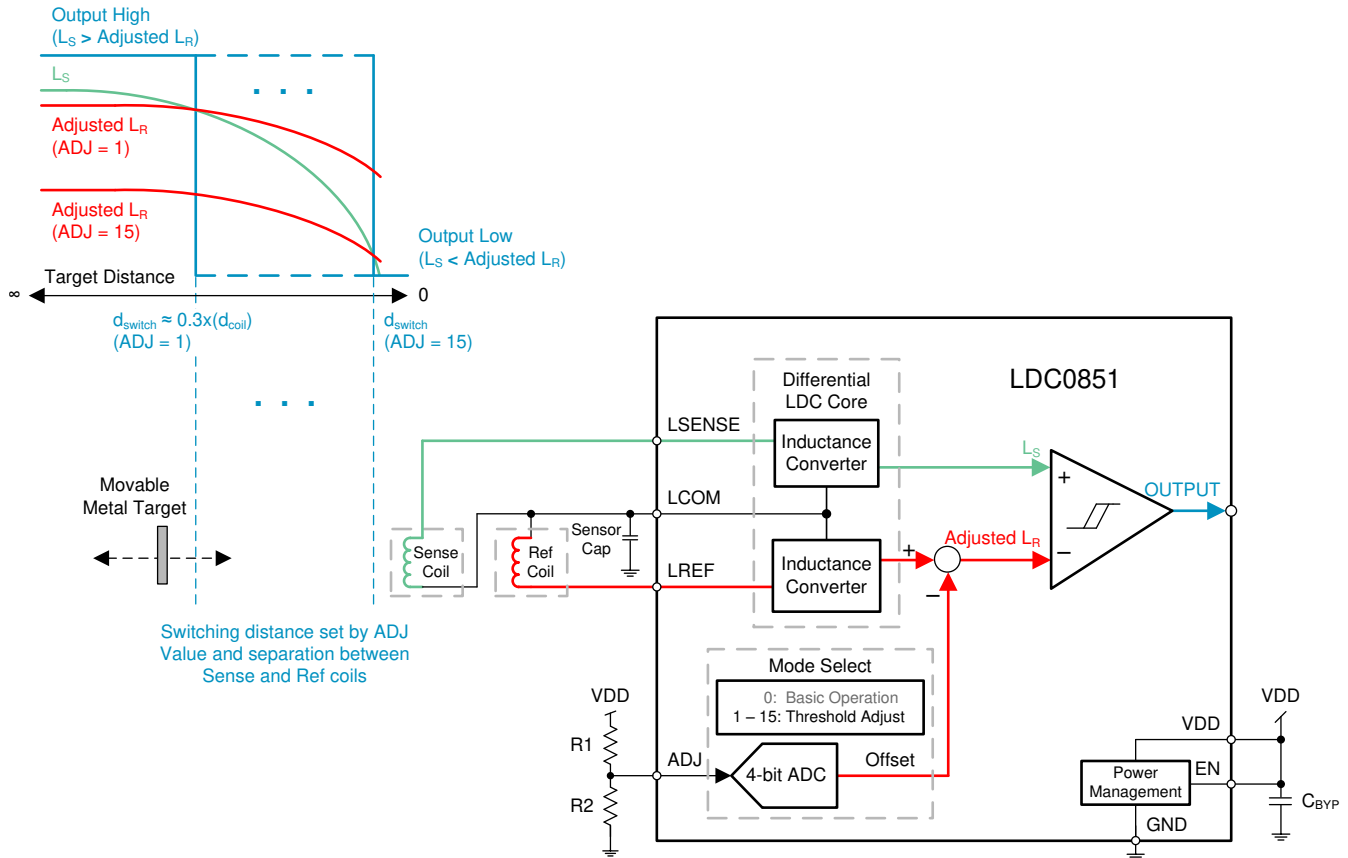**図 6-4. Threshold Adjust Mode for Distance Sensing Using Stacked Coils**

To get the most sensing range with stacked coils the spacing between the sensing coil and reference coil (height = h) should be maximized as shown in 図 6-5. See section *Stacked Coils* for more information on the layout of stacked coils.

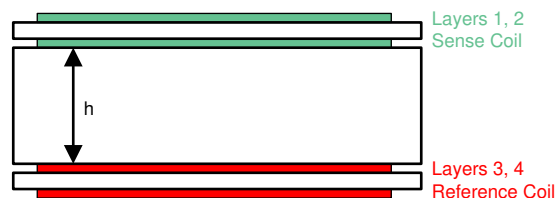**図 6-5. Stacked Coil Separation (PCB Side View)**

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English Data Sheet: SNOSCZ7

6.3.3 Setting the Threshold Adjust Values

To configure a threshold setting, connect a 49.9 kΩ resistor (R1) between VDD and the ADJ pin as shown in 図 6-4. The threshold is determined by the value of R2 as shown in the 表 6-1 below. R1 and R2 should be 1% or tighter tolerance resistors with a temperature coefficient of <50 ppm/°C.

表 6-1. Resistor Values for ADJ Code

ADJ Code	R2 (kΩ)
1	3.32
2	5.11
3	7.15
4	9.31
5	11.5
6	14
7	16.5
8	19.6
9	22.6
10	26.1
11	30.1
12	34
13	39
14	44.2
15	49.9

The switching distance for each ADJ code can be approximated with the following formula:

$$d_{switch} = d_{coil} \times 0.4 \times \left(1 - \frac{ADJ_{Code}}{16}\right)$$

(1)

where:

- d_{switch} is the approximated switching distance threshold
- d_{coil} is the coil diameter, in the same units as d_{switch}
- ADJ_{Code} is the desired value from 表 6-1

For example, consider a coil with a diameter of 10 mm: An ADJ code of 1 will yield a switching distance of 3.75 mm and for a code of 15 a switching distance of 0.25 mm. This method helps reduce the effort needed to design the coil ratio precisely for a specific switching distance. It should be noted that the maximum sensing distance is determined almost entirely by the diameter of the coil for circular coils or by the minimum outer dimension for rectangular coils.

6.3.4 Hysteresis

The LDC0851 includes hysteresis for the switching threshold. The switch point is determined by the inductance ratio between LSENSE and LREF. When the ratio of LSENSE to LREF drops below 99.6%, the device switches ON (output low). When LSENSE/LREF becomes greater than 100.4% it switches OFF (output high). The hysteresis window is therefore specified 0.8% from the switch ON point.
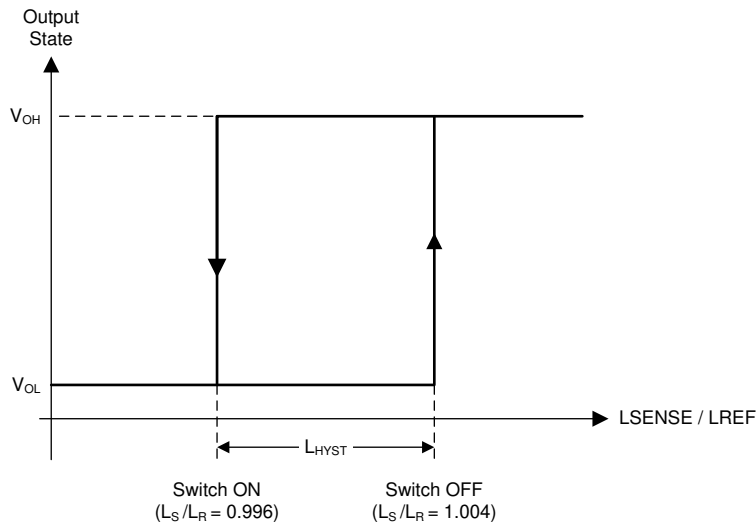

図 **6-6. Inductance Hysteresis**

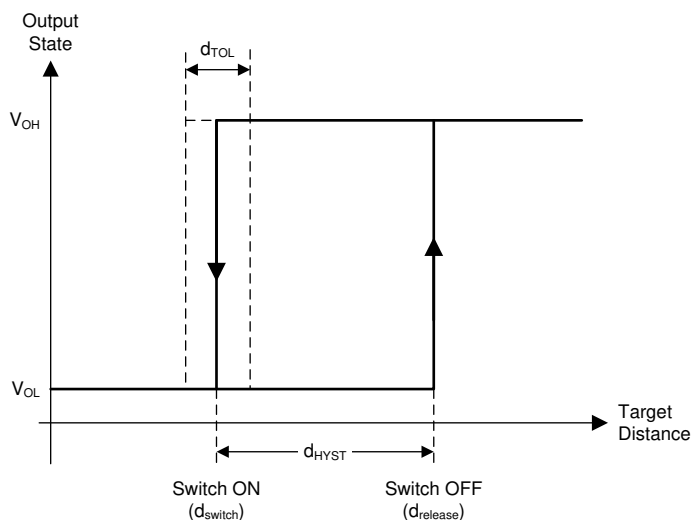For proximity sensing, hysteresis may also be approximated in terms of distance as shown in 図 *6-7*.

図 **6-7. Switching Distance Hysteresis and Threshold Tolerance**

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English Data Sheet: SNOSCZ7

6.3.5 Conversion Time

The length of time for the LDC0851 to complete one conversion and update the output is called the conversion time and is a function of sensor frequency. The conversion time is calculated with the following equation:

$$t_{CONVERSION} = \frac{1}{231.0 \times 10^{-6} \times f_{SENSOR}}$$

(2)

where:

- $t_{CONVERSION}$ is the conversion time interval
- f_{SENSOR} is the sensor frequency given by 式 6

It is important to note that the frequency of the sensor increases in the presence of conductive objects. Therefore the worst case conversion time is calculated with no target present or when the target is at the maximum distance from the sensor.

6.3.6 Power-Up Conditions

This indicates the switch output state when there is no metal target within the switching distance of LDC0851. On power-up the LDC0851 output will be held HIGH until the part performs the sensor test and is ready for normal operation. This remains true even if the enable pin (EN) is pulled low. A HIGH to LOW transition on the OUT line occurs when the metal target comes within the switching distance of LDC0851. In the case of any sensor fault condition the LDC0851 maintains a HIGH state. An example of a sensor fault is if the sensor gets disconnected or damaged.
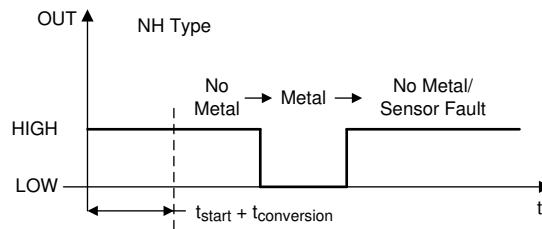

図 6-8. Output Status at Power up and in Presence of Metal Target

6.4 Device Functional Modes

6.4.1 Shutdown Mode

To save power, the LDC0851 has a shutdown mode. In order to place the LDC0851 in shutdown mode set the EN (Enable) pin low. This mode is useful for low power applications where the EN pin can be duty cycled at a low rate for wake-up applications to achieve a very low average supply current. An example of a duty-cycled application can be found in the applications section *Low Power Operation*. To resume active operation, set EN high and wait $t_{AMT} + t_{DELAY}$ for valid output data. The current consumption in this mode is given in the electrical table as I_{SD}. Note that the output will remain high (OFF) when EN is low. See *Power-Up Conditions* for more information on the startup conditions.

6.4.2 Active Mode

When the LDC0851 EN pin is pulled high, the LDC0851 is put into active mode. The active supply current (I_{DD}) is broken up into three pieces: Static current (I_{static}), Dynamic current (I_{dyn}), and Sensor current (I_{sensor}).

Static current is the DC device current given in the electrical characteristics and does not vary over frequency.

Dynamic current is the AC device current which varies with both sensor frequency (f_{SENSOR}) and board parasitic capacitance (C_{BOARD}). Dynamic current can be computed with the following equation:

$$I_{dyn} = (24.262 \times 10^{-12}) \times f_{SENSOR} + 1.5 \times f_{SENSOR} \times C_{BOARD}$$

(3)

where:

- I_{dyn} is the dynamic current drawn by the device and board parasitics
- f_{SENSOR} is the sensor frequency calculated from 式 6
- C_{BOARD} is the parasitic capacitance of the board, see 図 7-1

Sensor current is the AC current required to drive an external LC sensor. Sensor current varies with both the frequency and inductance of the sensor and is given by the following equation:

$$I_{sensor} = \frac{1}{17.1 \times L_{SENSOR} \times f_{SENSOR}}$$

(4)

where:

- I_{SENSOR} is current required to drive the sensor
- L_{SENSOR} is the measured inductance of the sensor
- f_{SENSOR} is the sensor frequency calculated from 式 6

The total active supply current is given by the following equation:

$$I_{DD} = I_{dyn} + I_{static} + I_{sensor}$$

(5)

where:

- I_{DD} is the total active supply current
- I_{dyn} is the dynamic current drawn by the device as given by 式 3
- I_{static} is the static current as given in the electrical table
- I_{SENSOR} is current required to drive the sensor as given by 式 4

English Data Sheet: SNOSCZ7

7 Application and Implementation

7.1 Application Information

7.1.1 Sensor Design

The LDC0851 relies on two externally placed sensors (L_{SENSE} and L_{REF}) and a capacitor (C_{SENSOR}) for proper operation. The design and matching of the coils is very critical to ensure a proper switching occurrence. It is also important to note that the parasitic capacitance of the board (C_{BOARD}) and of the LCOM input pin (C_{IN_COM}) are in parallel with C_{SENSOR}, and the sum of all three capacitances create a total capacitance (C_{TOTAL}) which is considered part of the system. C_{TOTAL} must be greater than 33 pF to be considered in the valid design space.
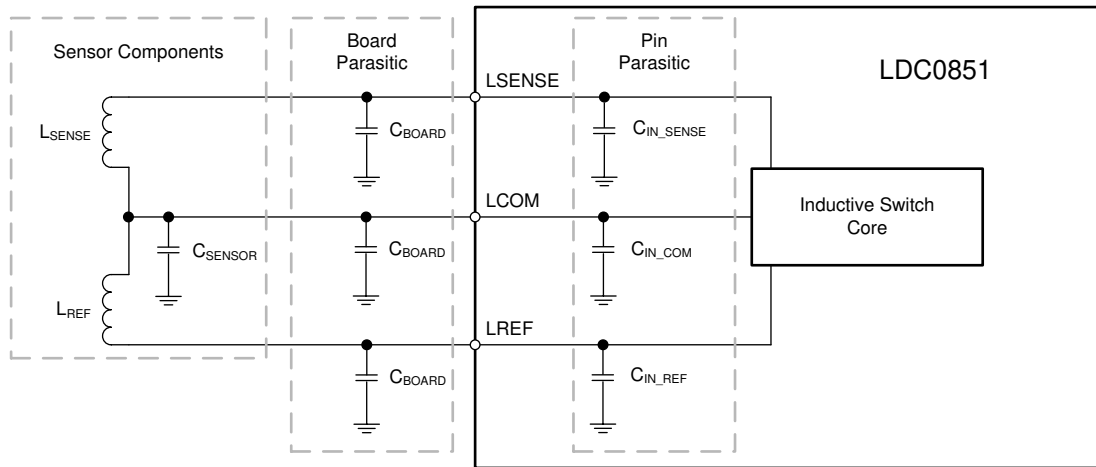
図 7-1. Sensor Components, Board Parasitics, and Package Parasitics Diagram

7.1.1.1 Sensor Frequency

The sensor frequency is calculated with the following equation.

$$f_{SENSOR} = \frac{\sqrt{2}}{2\pi \times \sqrt{L_{SENSOR} \times C_{TOTAL}}}$$

(6)

where:

- f_{SENSOR} is the calculated oscillation frequency with no target present
- L_{SENSOR} is the inductance of the sense coil or reference coil
- C_{TOTAL} is sum of external sensor, board parasitic, and pin parasitic capacitances connected to LCOM, refer to 図 7-1

7.1.1.2 Sensor Design Procedure

The following procedure should be followed for determining the sensor characteristics:

1. Determine the diameter of coil (d_{coil}), which should be 3 times larger than the desired switching distance (d_{switch})
2. Determine the desired frequency (f_{SENSOR}) which should be between 300 kHz and 19 MHz
3. Calculate the range of allowable inductance from the following equation:

$$L_{SENSOR} \geq \frac{1}{4.83 \times (f_{SENSOR}) \times (I_{SENSOR\_MAX})}$$

(7)

where:

- L_{SENSOR} is the inductance of the LSENSE coil or LREF coil
- I_{SENSOR_MAX} is given in the electrical table

4. Calculate the externally placed sensor capacitor:

$$C_{SENSOR} = \frac{1}{(\pi \times f_{SENSOR})^2 (2 \times L_{SENSOR})} - C_{BOARD} - C_{IN\_COM}$$

(8)

where:

- C_{BOARD} is the parasitic capacitance introduced by the board layout (~4 pF for good layout)
- C_{IN_COM} is the parasitic pin capacitance of LCOM specified as 12 pF in the electrical table

Product Folder Links: *LDC0851*

English Data Sheet: SNOSCZ7

7.2 Typical Application

7.2.1 Event Counting

The LDC0851 can be used for event counting applications such gear tooth detection or rotational speed measurements. An example of gear tooth detection using side by side coils is shown below where the gear is made of a conductive material and rotates over the coils. Two identical coils can be placed such that when one of the coils is covered by a gear tooth, the other is uncovered. The output will toggle when the inductance values of both coils are equal as the gear passes by.
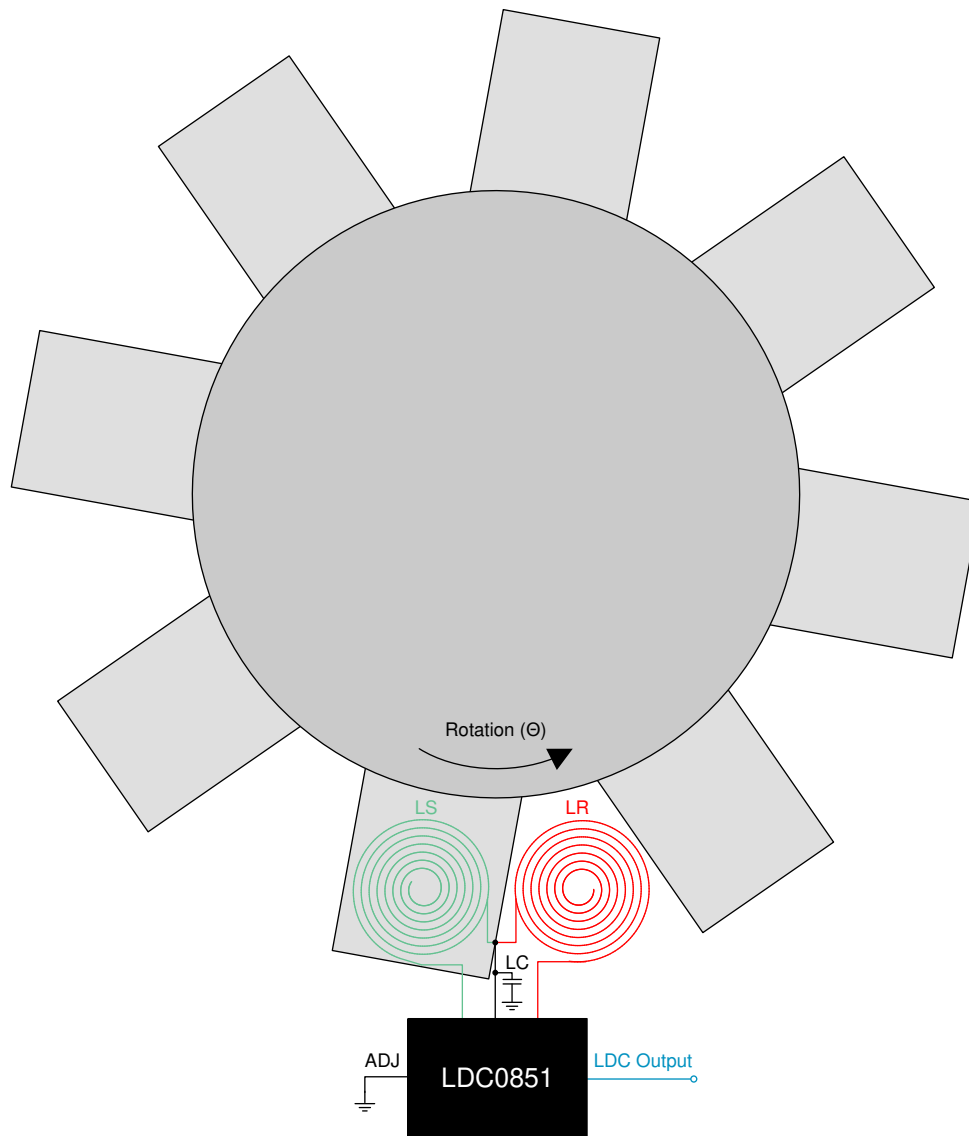

図 7-2. Gear Tooth Functional Diagram

7.2.1.1 Design Requirements

Assume a gear with 8 conductive teeth is used in a system to determine flow rate. Determine the maximum speed that can be reliably detected by the LDC0851 using a sensor frequency of 15 MHz.

7.2.1.2 Detailed Design Procedure

To ensure a reliable reading an event must be sampled twice when the gear tooth covers more of the LSENSE coil than the LREF coil (LS<LR) producing a LOW output and equivalently twice when the gear tooth covers

more of LREF than LSENSE (LR<LS) producing a HIGH output. The maximum speed can be achieved when the output toggles at a duty cycle rate of 50%. This can be achieved by using a gear where the width of each tooth is the same as the width of the gaps between the teeth. For asymmetric systems, the minimum width of either the gap or the gear tooth determines the maximum detectable speed. For symmetrical systems, the maximum rotational speed that can be reliably detected in revolutions per minute (rpm) for a given number of gear teeth can be determined by the following formula:

$$\text{Gear Speed (rpm)} = \frac{1}{4} \times \left[f_{\text{SENSOR}} \times \left(231.0 \times 10^{-6}\right) \right] \times \left(\frac{60}{\text{\# gear teeth}} \right)$$

(9)

where:

- Gear Speed (rpm) is the calculated speed of the gear
- f_{SENSOR} is the sensor frequency given by 式 6
- \# gear teeth is the total number of events per rotation

A gear with 8 teeth and sensor frequency of 15MHz could reliably measure a gear rotational speed of 6500 rpm.

7.2.1.3 Application Curves

The metal coverage has an inverse relationship to coil inductance. 図 7-3 shows the relationship between the output of the LDC0851 and relative inductance of the coils as the gear is rotating.
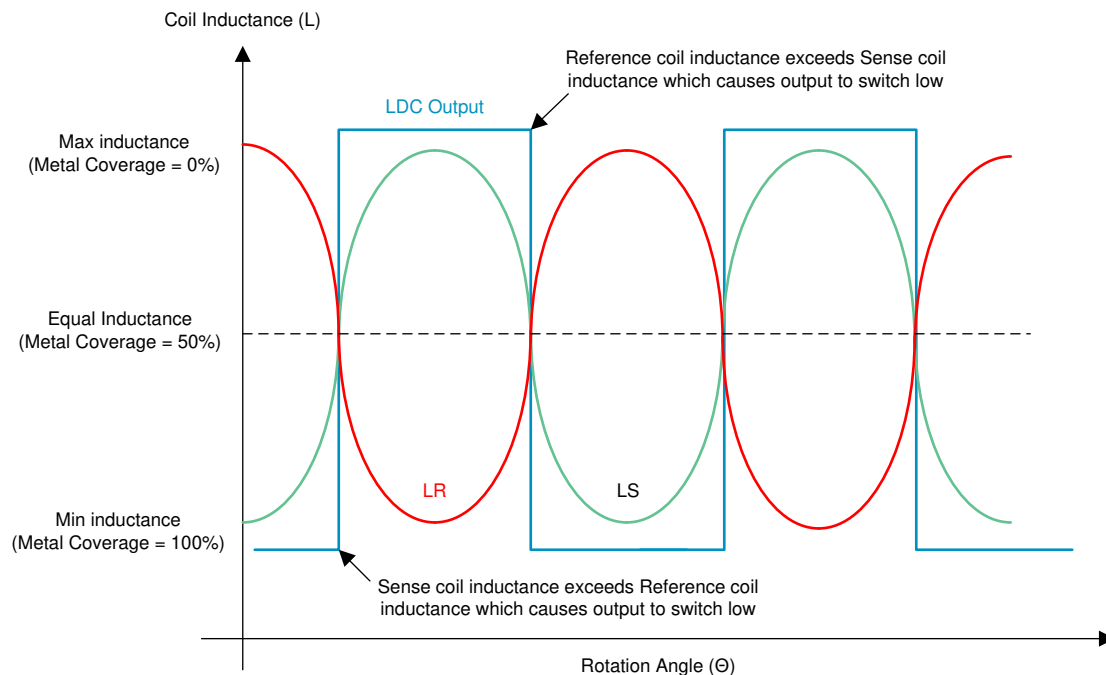

図 7-3. Angular Position vs Coil Inductance

7.2.2 Coarse Position Sensing

The LDC0851 may be used for coarse proximity sensing such as a push button application. A conductive target may be added to the underside of a mechanical push button as shown below.
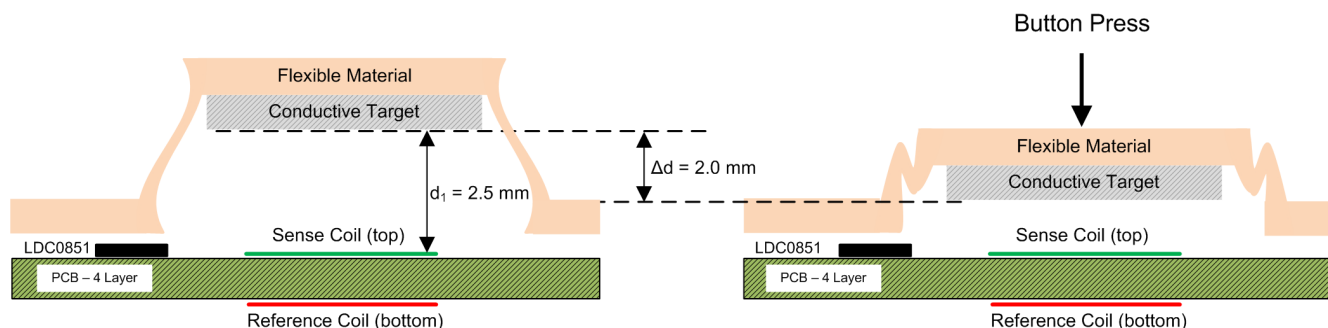

図 7-4. Coarse Position Sensing Side View

7.2.2.1 Design Requirements

A push button that is made of flexible material has a conductive target attached to the underside and a contactless solution using the LDC0851 is required for reliability purposes. Determine the coil characteristics as well as the threshold adjust setting if the following conditions are true:

1. The target is made of a conductive material, such as aluminum foil or copper tape
2. The conductive target is circular and measures 10 mm in diameter
3. The resting height of the conductive target is 2.5 mm above the PCB when no button push
4. The maximum travel distance when pressed is 2 mm, leaving an airgap of 0.5mm above the PCB

7.2.2.2 Detailed Design Procedure

To conserve PCB area, a 4 layer stacked coil approach is used with the sense coil on the top 2 layers and reference on the bottom 2 layers. The LDC0851 switching threshold is then determined by following parameters:

1. Conductive Target Size: The best response is achieved when the target area is ≥100% compared to the coil area.
2. Coil diameter: The diameter of the coil should be at least 3x greater than the desired switching distance.
3. ADJ code: Increasing ADJ code linearly scales down the switching distance estimated by 式 1.

The coil diameter should not exceed the diameter of the conductive target of 10mm in order to keep the target-to-coil coverage ≥100%. Additionally, in order to detect the lightest button pushes where the conductive target rests at a height of 2.5 mm, the coil should be at least 3 times greater giving a minimum size of 7.5 mm. The user may therefore select a coil size between 7.5 mm and 10 mm. A coil diameter of 10mm is chosen for the most flexibility and tuning range. The response versus ADJ code is shown below in 図 7-5.

In this example the deflection caused by the button press (Δd) is 2mm. Note that the Δd must be enough to cross the "Switch ON" threshold and return past "Switch OFF" threshold of the LDC0851 for a given ADJ code to be considered a valid code. Codes 0 through 6 should not be used because the conductive target has already crossed the "Switch ON" thresholds and would always be in the ON state without a button push. Similarly code 15 should not be used because the output would always be in an OFF state regardless of how hard the button is pushed. Therefore codes 8 through 14 are clearly inside the travel distance of the button. Select code 8 to detect light button pushes, code 11 for medium button pushes, or code 14 to only detect strong button pushes. Once the ADJ code is selected based on user preference, set the resistor divider R1 and R2 values according to section *Setting the Threshold Adjust Values*.
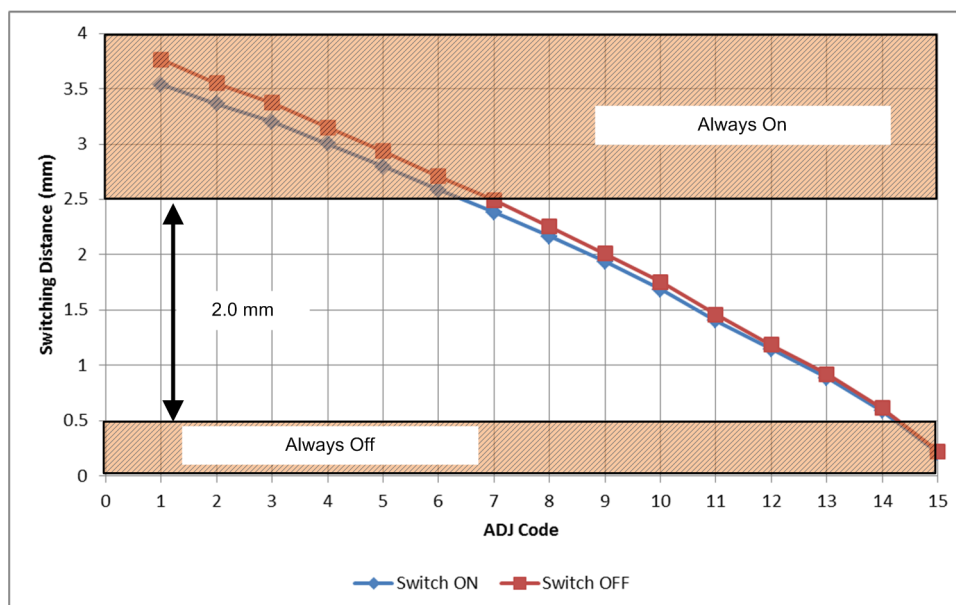
7.2.2.3 Application Curves

図 7-5. Threshold Adjust Design Space for 10mm Coil Example

Product Folder Links: *LDC0851*

English Data Sheet: *SNOSCZ7*

7.2.3 Low Power Operation

It may be desirable to operate the LDC0851 on battery power and take samples at a very low sample rate, such as portable sensor devices or intruder detection systems. By using a nanotimer (ultra low power timer) such as the TPL5110 or a microcontroller such as the MSP430F5500 it is possible to duty cycle the EN pin of the LDC0851 as shown in the application schematic in 図 7-6.
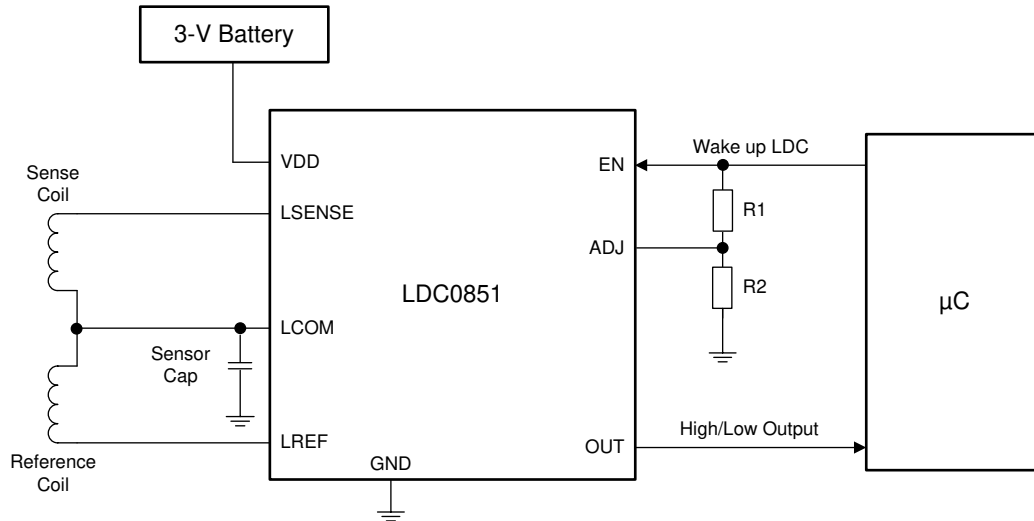

図 7-6. Application Schematic Showing Low Power Operation

7.2.3.1 Design Requirements

The LDC0851 is used in a low power, battery operated system to detect when a window is opened. Determine the average supply current of the LDC0851 if following requirements exist:

1. A lifetime of greater than 10 years is required from a single CR2032 battery which supplies the power for the LDC0851.
2. A microcontroller can be used to wake up the LDC0851 and capture the high/low output state.
3. At least 1 sample per second (f_{SAMPLE}) is required to detect if the window is open or closed.

7.2.3.2 Detailed Design Procedure

In order to achieve 10 year lifetime out of a single CR2032 battery, the enable pin (EN) of the LDC0851 can be duty cycled to achieve a low average supply current. Refer to 図 7-7 to see the three different states of LDC0851 supply current during duty cycle operation. The sum of the Standby, Ramp, and On currents can be used to calculate the average supply current of the LDC0851, which needs to be below 2.5 µA to achieve a 10 year lifetime from a 220 mAh CR2032 battery.

The average supply current can be calculated in the following steps:
1. Select desired system sample rate (f_{SAMPLE}) based on the given application. In this example, f_{SAMPLE} is 1 sample per second.
2. Select the sensor characteristics (f_{SENSOR}, L_{SENSOR}, C_{SENSOR}) based on conversion time and current consumption.
    a. f_{SENSOR} should be increased as much as possible to minimize the conversion time. 10 MHz is chosen as a starting point.
    b. L_{SENSOR} should be increased as much as possible to decrease the sensor current (I_{SENSOR}). Based on a reasonable PCB area, 10 µH is a good starting point.
    c. C_{SENSOR} is calculated to be 34.5 pF from 式 8 using the inputs above. This makes C_{TOTAL} equal to 50.5 pF which meets the requirement of greater than 33 pF to be inside the design space.
3. Calculate the average active current:

$$I_{ON} = f_{SAMPLE} \times (2 \times t_{CONVERSION}) \times (I_{DD})$$ (10)

- where:
- f_{SAMPLE} is the number of samples per second given from step 1. In this example, f_{SAMPLE} is equal to 1.
- $t_{CONVERSION}$ is calculated from 式 2 to give a conversion time of 433 μs.
- I_{DD} is the total active supply current given by 式 5 to be 1.587 mA.
- I_{ON} is the active current consumed by the LDC0851 which comes to be 1.37 μA.

4. Calculate the average ramp current:

$$I_{RAMP} = f_{SAMPLE} \times (t_{AMT}) \times \left(\frac{I_{DD}}{2} \right)$$ (11)

- where:
- f_{SAMPLE} is the number of samples per second given from step 1. In this example, f_{SAMPLE} is equal to 1.
- t_{AMT} is the active mode transition time given in the electrical table as typically 450μs.
- I_{DD} is the total active supply current given by 式 5 to be 1.587 mA.
- I_{RAMP} is the current consumed by the LDC0851 before a conversion has started which comes to be 0.357 μA.

5. Calculate the average standby current:

$$I_{OFF} = (1 - f_{SAMPLE} \times (t_{AMT} - 2 \times t_{CONVERSION})) \times (I_{SD})$$ (12)

- where:
- f_{SAMPLE} is the number of samples per second given from step 1. In this example, f_{SAMPLE} is equal to 1.
- t_{AMT} is the active mode transition time given in the electrical table as typically 450μs.
- $t_{CONVERSION}$ is calculated from 式 2 to give a conversion time of 433 μs.
- I_{SD} is the shutdown current of the LDC0851 given in the electrical table as typically 140nA.
- I_{OFF} is the standby current of the LDC0851 which comes to be 0.140 μA.

6. Calculate the total average supply current:

$$I_{AVG} = I_{ON} + I_{RAMP} + I_{OFF}$$ (13)

- where:
- I_{ON} is the active supply current given from 式 10 to be 1.37 μA.
- I_{RAMP} is the ramp current given by 式 11 to be 0.357 μA.
- I_{OFF} is the standby current given by 式 12 to be 0.140 μA.
- I_{AVG} is the average supply current consumed per second which comes to 1.867 μA.

7. Finally the lifetime of the battery can be calculated:

$$\text{Battery Lifetime (years)} = \frac{\text{Battery Capacity}}{I_{AVG}}$$ (14)

- where:
- Battery Capacity is the amount of charge x time that the battery can hold in mAh. This example uses a CR2032 battery with 220 mAh.
- I_{AVG} is the value reported in 式 13 to be 1.867 μA.
- Battery Lifetime (years) is how long the battery will last reported in years which comes out to be 13.5 years with the inputs from above.

For example, using a sensor frequency of 10 MHz, sensor inductance of 10 μH, and 1 sample per second yields a lifetime of 13.5 years for a single CR2032 battery.

Product Folder Links: *LDC0851*

English Data Sheet: *SNOSCZ7*
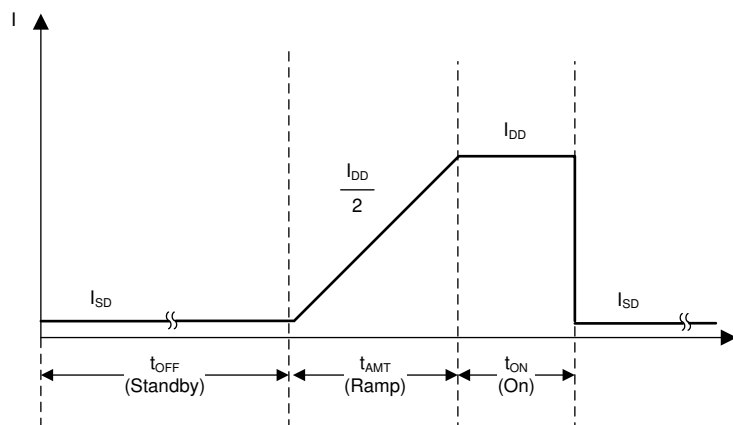
7.2.3.3 Application Curves

図 7-7. LDC0851 Supply Current vs. Time During Duty Cycle Operation

7.3 Power Supply Recommendations

A 0.1 µF capacitor should be used to bypass VDD. If multiple bypass capacitors are used in the system, then the smallest value capacitor should be placed as close as possible to the VDD pin. A ground plane is recommended to connect both the ground and the Die Attach Pad (DAP). If the supply ramp rate must be faster than 4.2 mV/µs the enable pin (EN) may be tied directly to VDD as shown in 図 7-8.
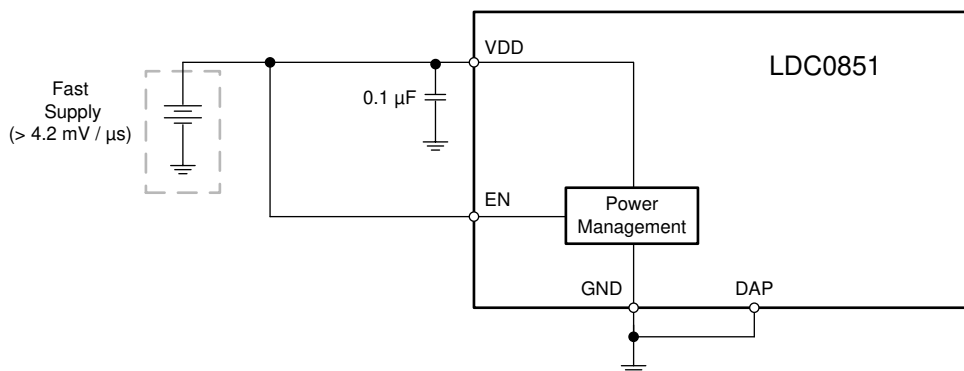

図 7-8. Supply Connections for Fast Ramp Rate

For supply ramp rates slower than 4.2 mV/µs, an RC low pass filter must be added to the enable input (EN) as shown in 図 7-9. Alternatively, the EN pin may be tied to a nanotimer or microcontroller to wake up the LDC0851 after VDD has ramped to its nominal value.
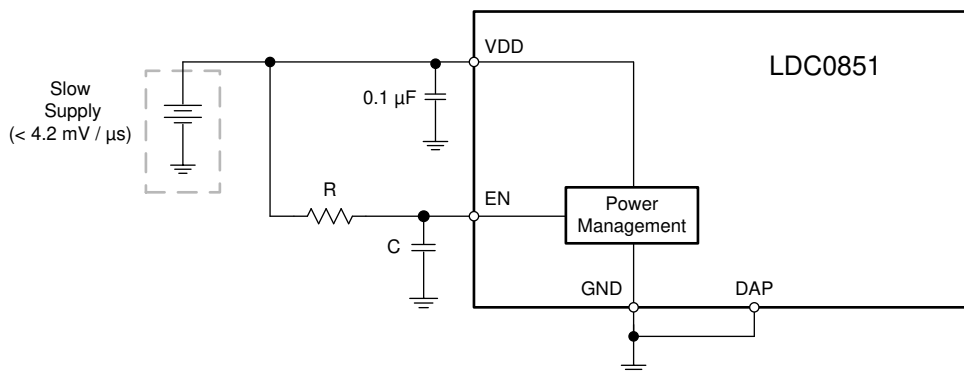

図 7-9. Supply Connections for Slow Ramp Rate

For applications that require low power, the EN pin may toggled with a GPIO or nanotimer to duty cycle the device and achieve ultra-low power consumption. Although the device may be power cycled to achieve a similar effect, some systems may not have a clean GPIO to supply the LDC0851 or the filtering on the supply may add a time constant delay which can make the use of the EN pin much more efficient and desirable for duty cycled applications. Refer to *Low Power Operation* for a detailed design example.

7.4 Layout

7.4.1 Layout Guidelines

The LDC0851 requires minimal external components for effective operation. An LDC0851 design should follow good layout techniques - providing good grounding and clean supplies are critical for optimum operation. Due to the small physical size of the LDC0851, use of surface mount 0402 or smaller components can ease routing. It is important to keep the routing symmetrical and minimize parasitic capacitances for LSENSE and LREF. The sensor capacitor should be placed close to the IC and keep traces far apart to minimize the effects of parasitic capacitance. For optimum performance, it is recommended to use a C0G/NP0 for the sensor capacitor.

7.4.2 Layout Example

7.4.2.1 Side by Side Coils

The use of side by side coils is recommended for many applications that require a 2 layer PCB or that require very accurate temperature compensation. For side by side coils it is recommended to put them on the same PCB, even if using a remote sensing application. This will keep the tolerances and mismatch between the coils as small as possible. An example layout of side by side coils is shown in 図 7-10.
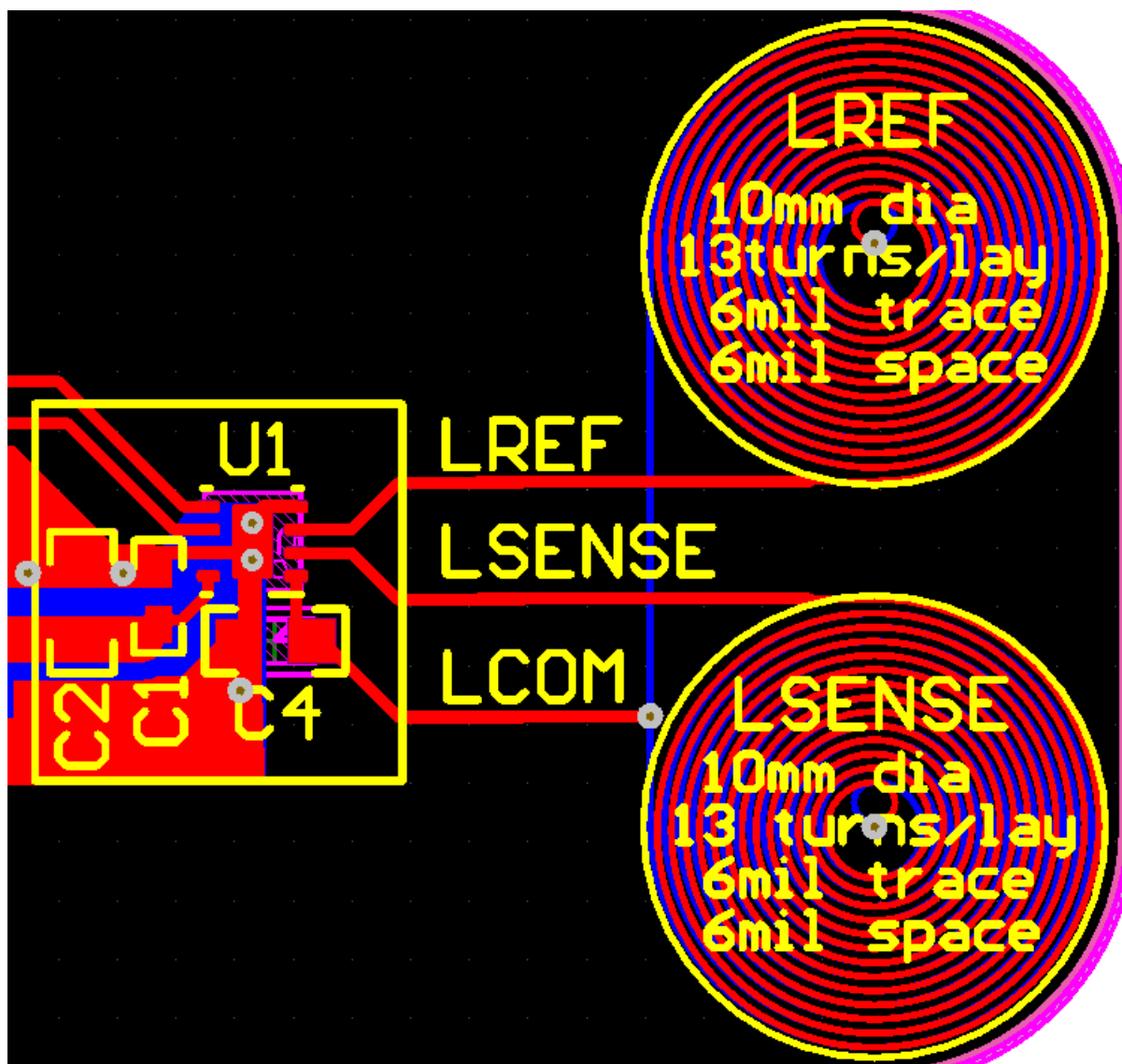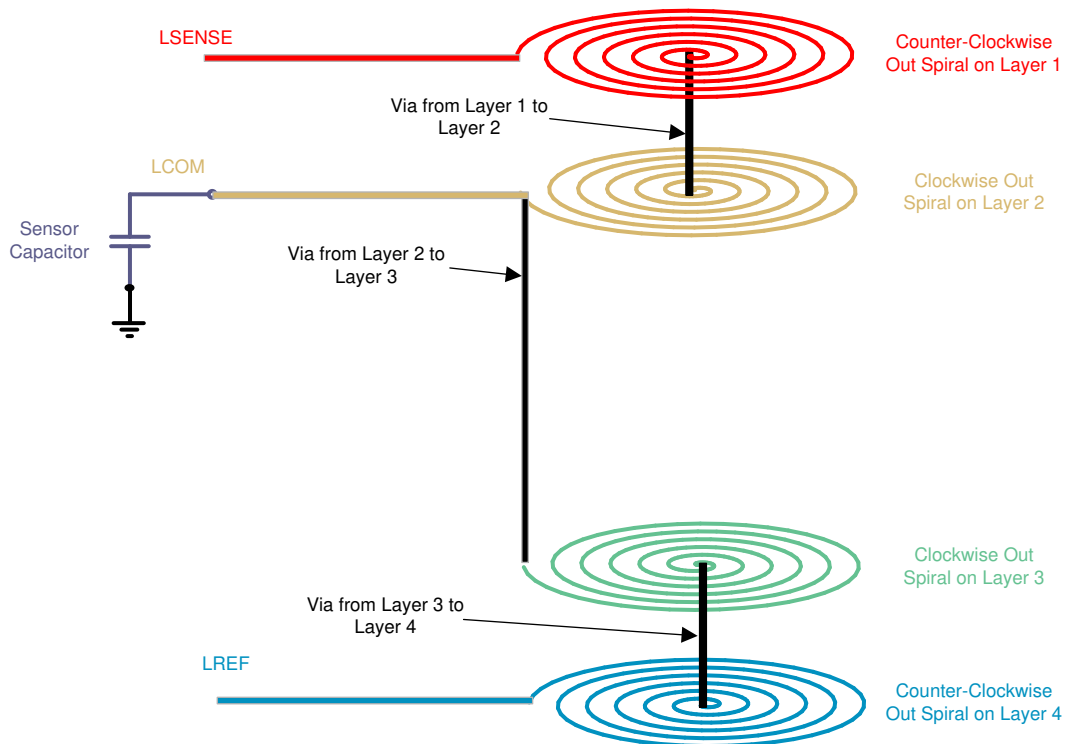
図 7-10. Side by Side Coil Layout Example

7.4.2.2 Stacked Coils

Use of stacked coils may be desirable to conserve board space and to prevent false triggering when a target approaches from the bottom. A 4 layer PCB with a thick inner layer is recommended to achieve the best results. It is important to note the direction and polarity of the sense coil and reference coils with respect to each other. The recommended configuration is shown below.

LSENSE

Counter-Clockwise Out Spiral on Layer 1

Via from Layer 1 to Layer 2

LCOM

Clockwise Out Spiral on Layer 2

Sensor Capacitor

Via from Layer 2 to Layer 3

Via from Layer 3 to Layer 4

Clockwise Out Spiral on Layer 3

LREF

Counter-Clockwise Out Spiral on Layer 4

図 7-11. Stacked Coil Recommended Connections and Direction

Product Folder Links: *LDC0851*

English Data Sheet: SNOSCZ7

8 Device and Documentation Support

8.1 Device Support

8.1.1 Development Support

For on-line LDC system design tools, see Texas Instruments' Webench® tool

The LDC Calculator tools provides a collection of calculation tools which run under MS Excel® useful for LDC system development.

8.2 Documentation Support

8.2.1 Related Documentation

The following resources contain additional information on the LDC0851 system design:
- Texas Instruments, *LDC Selection Guide*
- Texas Instruments, *LDC Sensor Design* application note
- Texas Instruments, *LDC Target Design* application note
- Texas Instruments, *LDC0851 - Troubleshooting* application note
- Texas Instruments, *LDC0851 Quick-Start Guide*

8.3 サポート・リソース

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8.6 用語集

テキサス・インスツルメンツ用語集　　　この用語集には、用語や略語の一覧および定義が記載されています。

9 Revision History

Changes from Revision A (January 2016) to Revision B (April 2024)	Page
• ドキュメント全体にわたって表、図、相互参照の採番方法を更新	1
• 「特長」セクションに機能安全の情報を追加	1
• 「アプリケーション」セクションを更新	1
• 「製品情報」表を「パッケージ情報」に変更	1
• Added *Related Documentation* section	31

Changes from Revision * (December 2015) to Revision A (January 2016)   **Page**

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: *LDC0851*

English Data Sheet: SNOSCZ7

PACKAGE OPTION ADDENDUM

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LDC0851HDSGR	Active	Production	WSON (DSG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	0851
LDC0851HDSGR.A	Active	Production	WSON (DSG) | 8	3000 | LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	0851
LDC0851HDSGT	Obsolete	Production	WSON (DSG) | 8	-	-	Call TI	Call TI	-40 to 125	0851

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION

REEL DIMENSIONS

Reel Diameter

Reel Width (W1)

TAPE DIMENSIONS

K0 P1 W B0 Cavity A0

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

Sprocket Holes

Q1 Q2 Q3 Q4

User Direction of Feed

Pocket Quadrants

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LDC0851HDSGR	WSON	DSG	8	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2

PACKAGE MATERIALS INFORMATION

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LDC0851HDSGR	WSON	DSG	8	3000	182.0	182.0	20.0

This image is a representation of the package family, actual package may vary.
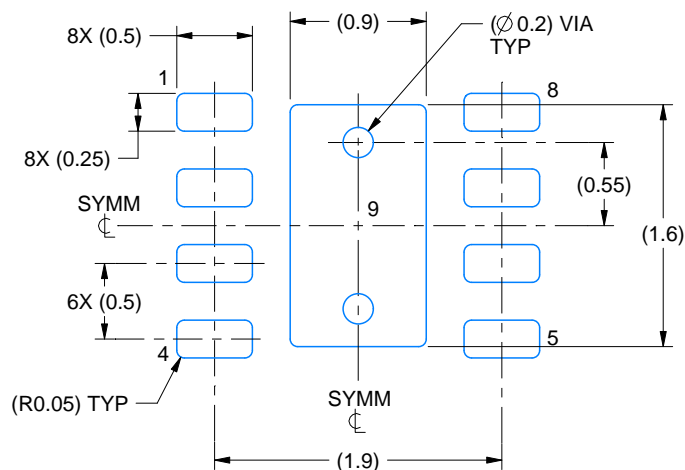Refer to the product data sheet for package details.

4224783/A

A 2.1 1.9 B

PIN 1 INDEX AREA

2.1 1.9

0.32 0.18
0.4 0.2

ALTERNATIVE TERMINAL SHAPE
TYPICAL

0.8 0.7

0.05 0.00

C

SEATING PLANE

⌒ 0.08 C

SIDE WALL METAL THICKNESS DIM A	
OPTION 1	OPTION 2
0.1	0.2

EXPOSED THERMAL PAD

0.9 ± 0.1

4

5

6X 0.5

2X 1.5

9

1.6 ± 0.1

1

8

PIN 1 ID (45° X 0.25)

8X 0.4 0.2

8X 0.32 0.18

(DIM A) TYP

⊕	0.1 Ⓜ	C	A	B
	0.05 Ⓜ	C		
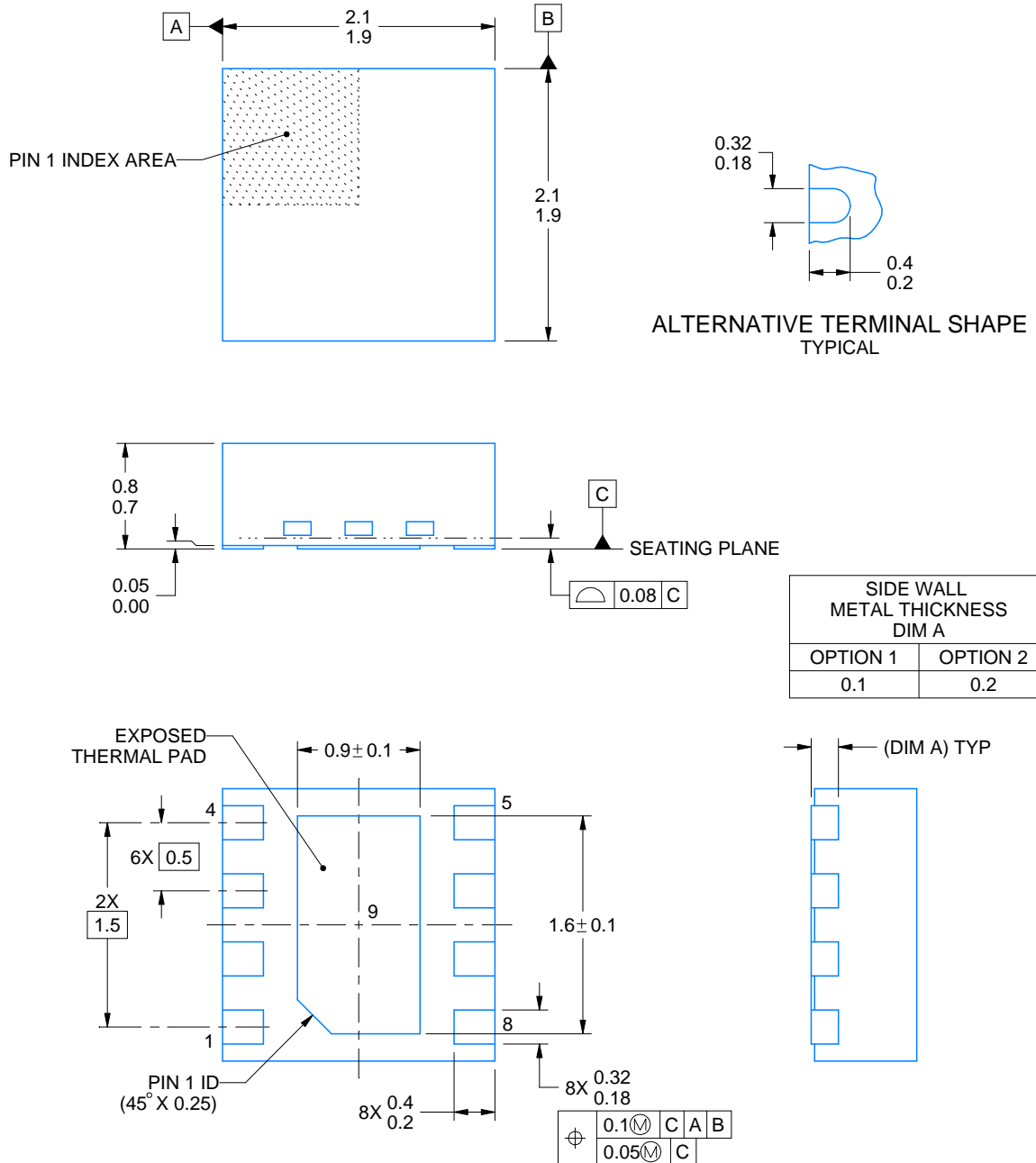
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NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

8X (0.5)

1

8X (0.25)

SYMM
℄

6X (0.5)

4

(R0.05) TYP

(0.9)

(∅ 0.2) VIA
TYP

8

9

(0.55)

(1.6)

5

SYMM
℄

(1.9)

LAND PATTERN EXAMPLE
SCALE:20X

0.07 MAX
ALL AROUND

SOLDER MASK
OPENING

METAL

NON SOLDER MASK
DEFINED
(PREFERRED)

0.07 MIN
ALL AROUND

METAL UNDER
SOLDER MASK

SOLDER MASK
OPENING

SOLDER MASK
DEFINED

SOLDER MASK DETAILS

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NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

8X (0.5)

1

8X (0.25)

SYMM

SYMM

METAL

8

(0.45)

9

6X (0.5)

4

(R0.05) TYP

(0.9)

(1.9)

(0.7)

5
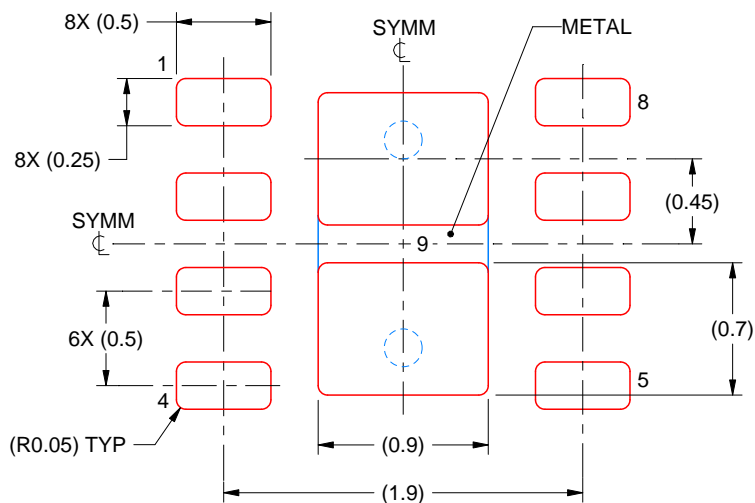
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 9:
87% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:25X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.